

# 3SK169

## Silicon N Channel 4-pole MOS Type

For VHF high-gain low-noise amplification mixers

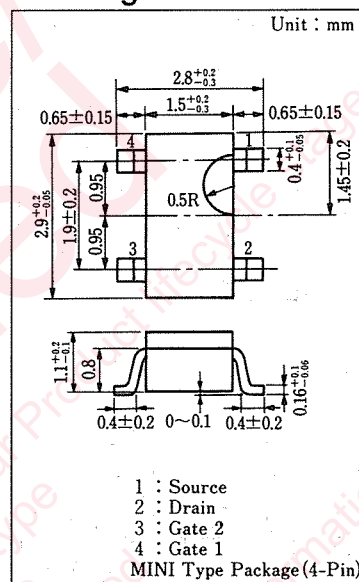
### ■ Features

- Large power gain PG
- A MINI type package that allows downsizing of equipment and automatic insertion by taping and magazine packaging

### ■ Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	15	V
Gate 1-Source Voltage	$V_{G1S}$	$\pm 8$	V
Gate 2-Source Voltage	$V_{G2S}$	$\pm 8$	V
Drain Current	$I_D$	30	mA
Power Dissipation	$P_D$	150	mW
Channel Temperature	$T_{ch}$	150	°C
Storage Temperature	$T_{stg}$	-55 ~ +150	°C

### ■ Package Dimensions



### ■ Electrical Characteristics (Ta=25°C)

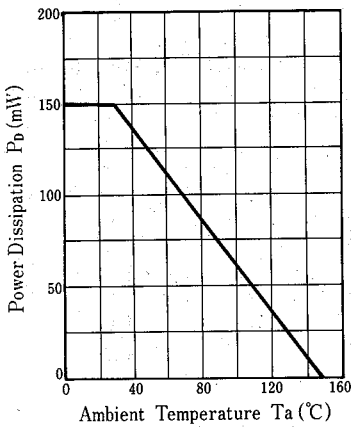
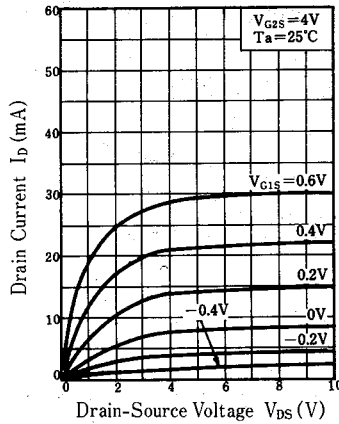
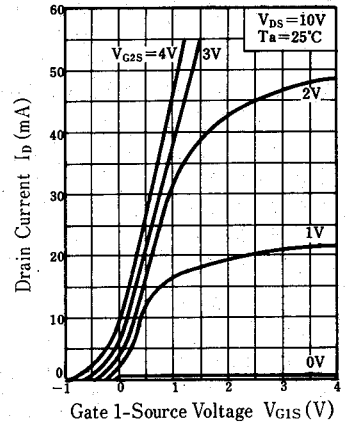
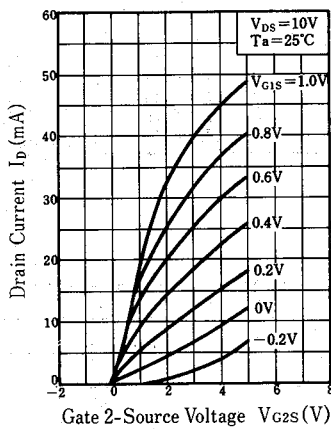
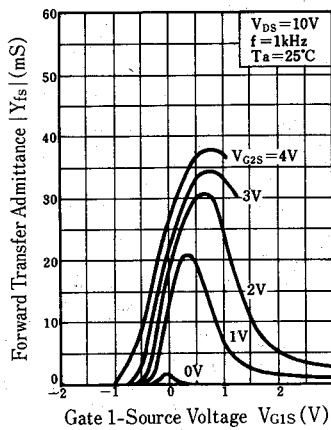
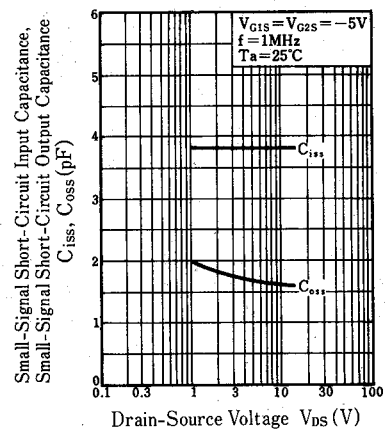
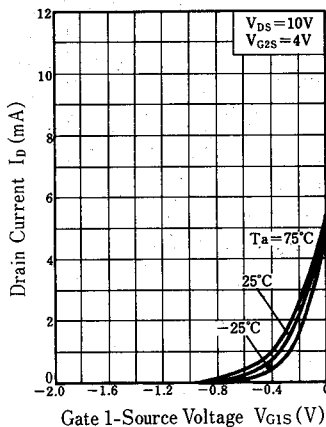
Item	Symbol	Condition	min.	typ.	max.	Unit
Drain Current	$I_{DSS}^*$	$V_{DS}=10V, V_{G1S}=0, V_{G2S}=4V$	1.5		10	mA
Gate 1 Cutoff Current	$I_{G1SS}$	$V_{DS}=0, V_{G2S}=0, V_{G1S}=\pm 8V$			$\pm 20$	nA
Gate 2 Cutoff Current	$I_{G2SS}$	$V_{DS}=0, V_{G1S}=0, V_{G2S}=\pm 8V$			$\pm 20$	nA
Drain-Source Voltage	$V_{DSK}$	$I_D=50\mu A, V_{G1S}=-5V, V_{G2S}=0$	15			V
Gate 1-Source Cutoff Current	$V_{G1S1}$	$V_{DS}=10V, V_{G2S}=4V, I_D=100\mu A$	-3		+0.5	V
Gate 2-Source Cutoff Current	$V_{G2S1}$	$V_{DS}=10V, V_{G1S}=0, I_P=100\mu A$	-2		+0.5	V
Forward Transfer Admittance (Common Source)	$ Y_{fs} $	$V_{DS}=10V, I_D=10mA, V_{G2S}=4V, f=1kHz$	23	30		mS
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{G1S}=-5V, V_{G2S}=-5V, f=1MHz$		4.5	5.7	pF
Output Capacitance	$C_{oss}$			1.7	2.2	pF
Small-Signal Reverse Transfer Capacitance	$C_{rss}$			0.02		pF
Gain Reduction	CG	$V_{DS}=8V, V_{G2S}=3V, I_D=1mA, f=200MHz, f_{LO}=245MHz, P_{LO}=10dBm$	13	17		dB

\* $I_{DSS}$  Ranking

Rank	P	Q
$I_{DSS}$ (mA)	1.5~5	3~10
Marking	3FP	3FQ

### ■ Type Name Marking (Example)

Type No.  $I_{DSS}$  Ranking

$P_D - T_a$  $I_D - V_{DS}$  $I_D - V_{G1S}$  $I_D - V_{G2S}$  $|Y_{fs}| - V_{G1S}$  $C_{iss}, C_{oss} - V_{DS}$  $I_D - V_{G1S}$ 

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